Chem 5390 Advanced X-ray Analysis

LECTURE 14

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Diffraction Methods

3. Diffractometer (Powder) Method

What can we learn from the diffractometer experiments?

Phase Analysis

Texture Analysis

Lattice Parameters

Crystallite Size

Stress Analysis

Strain Analysis



Phase Analysis - Vegard's Law

Good for alloys with continuous solid solutions

$$d_{hkl} = \sqrt{\frac{a^2}{h^2 + k^2 + l^2}}$$

Ex) Au-Pd

- To create the plot on the right
 - Using the crystal structure of the alloy calculate "a" for each metal
 - Draw a straight line between them as shown on the chart to the left.
- To calculate the composition
 - Calculate "a" from d-spacings
 - "a" will be an atomic weighted fraction of "a" of the two metal

Figure 11-6 Lattice parameters of some continuous solid solutions. Dot-dash lines indicate Vegard's law. Barrett [1.7].



Measuring Changes In Phase Fraction

Using I/Icor

$$\frac{I_{\alpha-\exp}(hkl)}{I_{\beta-\exp}(HKL)} = \frac{I_{\alpha}(hkl) \times \frac{I}{I_{cor\beta}}(hkl) \times w_{\beta}}{\frac{I}{I_{cor\alpha}}(hkl) \times I_{\beta}(hkl) \times w_{\alpha}}$$

-Where

- I _ Intensity of sample's 100% peak
- $\overline{I_{cor}} = \overline{I_{ntensity} of Corundum' s 100\% peak}$
- ω= weight fraction
- I(hkl)=Reference's relative intensity
- I_{exp}(hkl)=Experimental integrated intensity



Measuring Changes In Phase Fraction

Using Direct Comparison Method

$$\frac{I_{\alpha-\exp}(hkl)}{I_{\beta-\exp}(HKL)} = \frac{R_{\alpha} \times v_{\alpha}}{R_{\beta} \times v_{\beta}}$$
$$R = \frac{1}{V} \left[pCL_{P} [F_{hkl}]^{2} \right]$$
$$I_{hkl} = I_{0} pCL_{P} [F_{hkl}]^{2}$$

Because this is already a complicated method, many choose to go ahead and use Rietveld Refinement



Measuring Changes In Phase Fraction

Remember – changes in something like doping a sample can lead to changes in lattice parameters instead.



Measuring Changes In Phase Fraction

Substitutional doping can change bond distances, reflected by a change in unit cell lattice parameters

The change in peak intensity due to substitution of atoms with similar Z is much more subtle and may be insignificant



Diffraction Methods

3. Diffractometer (Powder) Method

What can we learn from the diffractometer experiments? Phase Analysis Texture Analysis Lattice Parameters Crystallite Size Stress Analysis Strain Analysis



Texture

Inducing texture in powder samples - causes peak intensities to vary

Large crystallite sizes and non-random crystallite orientations both lead to peak intensity variation The measured diffraction pattern will not agree with that expected from an ideal powder



Texture in samples is a common occurrence, and usually have more to do with how the samples are made.

Plastically deformed metals (cold rolled, etc)
Powders with particle shapes related to their crystal structure, particular planes form the faces
Orientation in particular directions (Plates, needles, acicular, cubes, etc.)



Orientation in particular directions (Plates, needles, acicular, cubes, etc.)

-Fiber Texture

- A particular direction [uvw] for all grains is more or less parallel to the wire or fiber axis
- e.g. [111] fiber texture in AI cold drawn wire
- Double axis is also possible
- Example: [111] and [100] fiber textures in Cu wire

-Sheet Texture

Most of the grains are oriented with a certain crystallographic plane (hkl) roughly parallel to the sheet surface and certain direction [uvw] parallel to the rolling direction Notation: (hkl)[uvw]

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-rav Analysis

Orientation in particular directions (Plates, needles, acicular, cubes, etc.)



 ⊕ [uvw] i.e. perpendicular to the surface of all grains is parallel to a direction [uvw] Also, if the direction $[u_1v_1w_1]$ is parallel for all regions, the structure is like a single crystal

However, the direction $[u_1v_1w_1]$ is not aligned for all regions, the structure is like a mosaic structure, also called as **Mosaic Texture**



Simple Means of Quantifying Texture Lotgering degree of orientation (*f*)

> A comparison of the relative intensities of a particular family of (hkl) reflections to all observed reflections in a coupled 2θ powder x-ray diffraction (XRD) Spectrum

> *f* is specifically considered a measure of the "degree of orientation" and ranges from 0% to 100%

po is p of a sample with a random crystallographic orientation.



Relative Texture Coefficient (RTC)

Relative peak intensities are analyzed by determining relative texture coefficients of the reflections present in the XRD pattern.

$$RTC_{hkl} = \frac{I_{p,hkl}/I^{\circ}_{p,hkl}}{\Sigma I_{p,hkl}/I^{\circ}_{p,hkl}} * 100\%$$

where I_{p,hkl} is the intensity of the peak for each sample at each (hkl) reflection used.

 $I_{p,hkl}^{\circ}$ is the intensity of those reflections for the standard reference (PDF# 00-000-0000) in the database.

The standard provides a random orientation pattern to compare against any preferred orientation found in the samples.

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Relative Texture Coefficient (RTC) Example: Golden et.al.



Table 2: Relative texture coefficients for (111), (200), (220), and (311) growth planes for each sample as measured with XRD.

RT	Sample	RTC200	RTC220	RTC 311			
4.:	A1	4.85	72.32	17.66			
4.	B1	4.32	71.84	15.74			
4.:	B2	4.27	72.66	15.26		chem	5390
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Relative Texture Coefficient (RTC) Example: Golden et.al.

Figure S10. X-ray diffraction (XRD) of (a) pure Ni, (b) Ni CeO₂, and (c) Ni Fc-CeO₂ coatings



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Table 2. XRD reflection intensities, relative texture coefficients, and crystallite sizes for Nickel, Ni CeO₂ and Ni Fc-CeO₂ electrodeposited coatings.

Coating (n=3)	I(f) ₁₁₁	I(f) ₂₀₀	I (f) ₂₂₀	RTC ₁₁₁	RTC ₂₀₀	RTC ₂₂₀	Crystallite size (nm)
PDF# 00-004-0850	100	42	21				
Nickel	49	100	3	29.8	63.3	6.9	47.6 ± 5.0
Ni CeO ₂	100	51	4	50.7	41.9	6.7	43.3 ± 6.3
Ni Fc-CeO ₂	100	11	16	63.1	14.6	22.3	32.0 ± 5.5

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Relative Texture Coefficient (RTC) Example: Golden et.al.



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Pole Figure Analysis

Texture Analysis Experiment

Measurement of texture (the non-random or preferred orientation of crystallites) involves measurement of the variations in intensity of a single Bragg reflection as the sample is both tilted (psi) and rotated (phi).

The result is plotted as a 'pole figure', in which the contours indicate intensity levels as a function of sample orientation.





Texture Analysis





Texture Analysis





Pole Figure Analysis

 θ_{B}

Example – thin films grown epitaxially on top of a substrate.

 θ_{B}

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Substrate

Film or Coating

Pole Figure Analysis

Epitaxial Films

- An epitaxial film is a lattice-matched thin film grown on usually a single crystal substrate
- The lattice of the film is nearly identical to the lattice of the substrate
- When the film grows, its lattice changes (strains) in order to match the lattice of the substrate
- The atomic bonding across the substrate and film is "perfectly" matched



Epitaxial Films

An epitaxial film is a lattice-matched thin film grown on usually a single crystal substrate



The lattice of the film (red) is almost the same as the substrate (blue)



The lattice of the epitaxial film (red) distorts to minimize the strain energy where it bonds to the substrate (blue)



Texture Analysis

Example: Bismuth Titanate thin films on oriented SrTiO₃ substrates

Only one type of peaks

It apparent that films are highly oriented

3 different examples



Pole Figure Analysis

SrTiO₃ (100)

SrTiO₃ (110)

$SrTiO_{3}$ (111)





- 4 Peaks at ~50°
- Excellent in-plane orientation

- 2 sets of peaks at \sim 5, 65 and 85°
- Indicating a doublet or opposite twin growth

- 3 sets of peaks at ~ 35 and 85°
- indicating a triplet or triple twin growth chem 5390

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Texture Analysis Evolution



Rocking Curves

A useful method for evaluating the quality of oriented samples such as epitaxial films.

- RC measurement reveals broadening of the diffraction peaks. The increase in the peak widths can be caused by:
 - -Mosaicity (misorientation of crystallites)
 - -Strain
 - -Limited layer thickness



Epitaxial Films – Mosaic Spread

Mosaicity is created by slight misorientations of different crystals as they nucleate and grow on the substrate. When the crystals join, they form low energy domain boundaries.



Ideal case, each nuclei (red) is perfectly oriented. When the crystals grow and meet, there is perfect bounding between the crystallites and therefore there is no grain boundary



If the nuclei (red) are slightly misaligned, then low angle domain boundaries will be formed.



Rocking Curves

Typically XRD peak width is quantitatively described by Full-Width-at Half-Maximum (FWHM).

 ω is changed by rocking the sample but θ_{B} is held constant

Width of Rocking curve is a direct measure of the range of orientation present in the irradiated area of the crystal





Summary

Perfect Epitaxy	Single crystal film in perfect registry with a substrate. There are no defects in the film or the substrate.
Nearly perfect epitaxy	Single crystal film in nearly perfect registry with a substrate. Both film and substrate contain a low concentration of defects. Most defects are dislocations in the film.
Textured epitaxial*	Film consists of mosaic domains in nearly perfect registry with the substrate. All domain boundaries are very low angle/low energy. There is nearly perfect bonding across domain boundaries.
Strongly textured polycrystalline	Film consists of grains with nearly perfect preferential orientation of all principle axes. This orientation is often strongly correlated to the substrate. Misorientation parameter for texture is small.
Textured polycrystalline	Film consists of grains with a preferred orientation for 3 principle axes or only along 1 axis out-of-plane.
Polycrystalline	Film consists of randomly oriented grains.
Amorphous	Film does not have long-range crystalline order.

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Summary

	Thickness	Composition	Lattice Strain/ Relaxation	Defects	Orientation	Residual Stress	Crystallite Size
Perfect Epitaxy	XRR, HRXRD	HRXRD, RC	Assume 100%	Assume none	HRXRD		
Nearly perfect epitaxy	XRR, HRXRD	HRXRD, RC	HRXRD	RC	HRXRD		
Textured epitaxial*	XRR, HRXRD	HRXRD	HRXRD, IP- GIXD	RC	HRXRD		
Strongly textured polycrystalline	XRR	XRPD, IP- GIXD	IP-GIXD	XRPD, IP-GIXD	IP-GIXD, PF	IP-GIXD	XRPD, IP- GIXD
Textured polycrystalline	XRR	XRPD, GIXD or IP- GIXD		XRPD, GIXD OR IP-GIXD	PF	Psi	XRPD, GIXD
Polycrystalline	XRR	XRPD, GIXD		XRPD, GIXD	PF	Psi	XRPD, GIXD
Amorphous	XRR						

XRR- X-Ray Reflectivity HRXRD- High Resolution XRD using coupled scan or RSM RC- Rocking CurveIP-GIXD- in-plXRPD- Bragg-Brentano powder diffractionPF- pole figureGIXD- grazing incidence XRDPsi- sin²psi usin

IP-GIXD- in-plane grazing incidence XRD PF- pole figure Psi- sin²psi using parellel beam

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Lab 3 – Due today

Lab 4 – Due 11-23-21

Reading Assignment:

Read Chapter 8 from: -X-ray Diffraction Procedures by Klug and Alexander

Read Chapter 13 from: -Elements of X-ray Diffraction, 3rd edition, by Cullity and Stock